
	<p>SI7852DP-T1-E3</p>
	<p>Hersteller-Teilenummer: SI7852DP-T1-E3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET N-CH 80V 7.6A PPAK SO-8</p> <p>Datenblätter:  SI7852DP-T1-E3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 23101 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI7852DP-T1-E3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET N-CH 80V 7.6A PPAK SO-8
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	23101 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	PowerPAK® SO-8
Supplier Device-Gehäuse	PowerPAK® SO-8
Verlustleistung (max)	1.9W (Ta)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	80V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	7.6A (Ta)
Rds On (Max) @ Id, Vgs	16.5 mOhm @ 10A, 10V
VGS (th) (Max) @ Id	2V @ 250µA (Min)
Gate Charge (Qg) (Max) @ Vgs	41nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	-
Antriebsspannung (Max Rds On, Min Rds On)	6V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)














SI7852DP-T1-E3 ist neu im Original, Suche SI7852DP-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI7852DP-T1-E3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI7852DP-T1-E3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI7852DP-T1-E3 Electro-Films (EFI) / Vishay MOSFET N-CH 80V 7.6A PPAK SO-8</p>	 <p>SI7852ADP-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 80V 30A PPAK SO-8</p>	 <p>SI7852DP-T1 VISHAY SI7852DP-T1 VISHAY</p>	 <p>SI7852ADP-T1-GE3 Vishay / Siliconix MOSFET N-CH 80V 30A PPAK SO-8</p>
 <p>SI7852DY-T1 VISHAY SI7852DY-T1 VISHAY</p>	 <p>SI7852ADP-T1-E3 Electro-Films (EFI) / Vishay MOSFET N-CH 80V 30A PPAK SO-8</p>	 <p>SI7852DP-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 80V 7.6A PPAK SO-8</p>	 <p>SI7852DP VISHAY SI7852DP VISHAY</p>

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|  SI7846DP-T1-E3 |  SI7846DP-T1-GE3 |  SI7846DP-T1-GE3 |  SI7846DP-T1 |  SI7846SAC |
|  SI7848BDP-T1-E3 |  SI7848BDP-T1-E3 |  SI7848BDP-T1-GE3 |  SI7848BDP-T1-GE3 |  SI7848DP |
|  SI7848DP-T1-E3 |  SI7848DP-T1-E3 |  SI7848DP-T1-GE3 |  SI7850DP |  SI7850DP-T1-E3 |
|  SI7850DP-T1-E3 |  SI7850DP-T1-GE3 |  SI7850DP-T1-GE3 |  SI7852ADP |  SI7852ADP-T1-E3 |
|  SI7852ADP-T1-E3 |  SI7852ADP-T1-GE3 |  SI7852ADP-T1-GE3 |  SI7852DP |  SI7852DP-T1-E3 |
|  SI7852DP-T1-GE3 |  SI7852DP-T1-GE3 |  SI7856ADP |  SI7856ADP-T1-E3 |  SI7856ADP-T1-E3 |
|  SI7856ADP-T1-GE3 |  SI7856ADP-T1-GE3 |  SI7856DP-T1 |  SI7856DP-T1-GE3 |  SI7856DP-T1-E3 |
|  SI7858ADP |  SI7858ADP-T1-E3 |  SI7858ADP-T1-E3 |  SI7858ADP-T1-GE3 |  SI7858ADP-T1-GE3 |
|  SI7858BDP |  SI7858BDP-T1-E3 |  SI7860ADP |  SI7860ADP-T1-E3 |  SI7860ADP-T1-E3 |
|  SI7860ADP-T1-GE3 |  SI7860ADP-T1-GE3 |  SI7860ADP-T1-E3 |  SI7860DP |  SI7860DP-T1 |

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